NSN 5961-01-029-1015

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-029-1015 **Inclosure Material:** Plastic **Overall Length:** Between 0.390 inches and 0.450 inches **Overall Height:** Between 0.070 inches and 0.130 inches Overall Width: Between 0.270 inches and 0.330 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 0.10 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No